

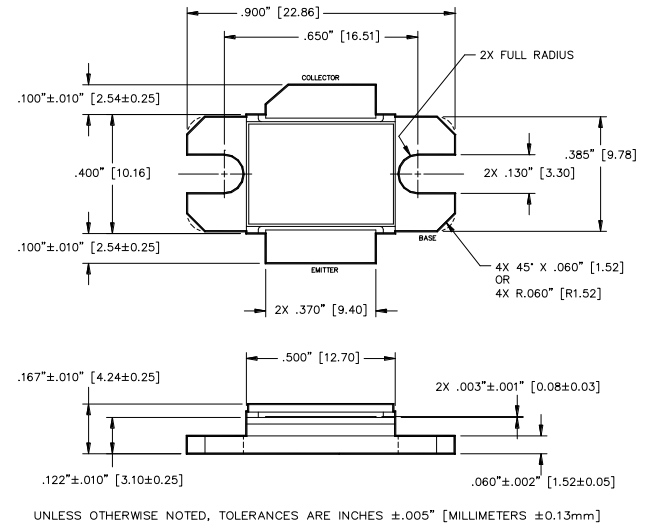
Radar Pulsed Power Transistor 170W, 2.7-2.9 GHz, 100µs Pulse, 10% Duty

Rev. V1

Features

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

Outline Drawing



Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V_{CES}	65	V
Emitter-Base Voltage	V_{EBO}	3.0	V
Collector Current (Peak)	I_C	27	A
Power Dissipation @ +25°C	P_{TOT}	500	W
Storage Temperature	T_{STG}	-65 to +200	°C
Junction Temperature	T_J	200	°C

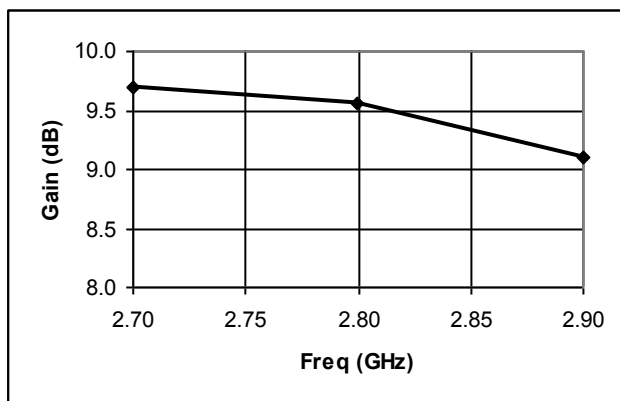
Electrical Specifications: $T_C = 25 \pm 5^\circ\text{C}$ (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	$I_C = 250\text{mA}$		BV_{CES}	65	-	V
Collector-Emitter Leakage Current	$V_{CE} = 40\text{V}$		I_{CES}	-	10	mA
Thermal Resistance	$V_{CC} = 36\text{V}$, $P_{in} = 24\text{W}$	$F = 2.7, 2.8, 2.9\text{ GHz}$	$R_{TH(JC)}$	-	0.35	°C/W
Output Power	$V_{CC} = 36\text{V}$, $P_{in} = 24\text{W}$	$F = 2.7, 2.8, 2.9\text{ GHz}$	P_{OUT}	170	-	W
Power Gain	$V_{CC} = 36\text{V}$, $P_{in} = 24\text{W}$	$F = 2.7, 2.8, 2.9\text{ GHz}$	G_P	8.5	-	dB
Collector Efficiency	$V_{CC} = 36\text{V}$, $P_{in} = 24\text{W}$	$F = 2.7, 2.8, 2.9\text{ GHz}$	η_C	40	-	%
Input Return Loss	$V_{CC} = 36\text{V}$, $P_{in} = 24\text{W}$	$F = 2.7, 2.8, 2.9\text{ GHz}$	RL	-	-10	dB
Load Mismatch Tolerance	$V_{CC} = 36\text{V}$, $P_{in} = 24\text{W}$	$F = 2.7, 2.8, 2.9\text{ GHz}$	VSWR-T	-	2:1	-
Load Mismatch Stability	$V_{CC} = 36\text{V}$, $P_{in} = 24\text{W}$	$F = 2.7, 2.8, 2.9\text{ GHz}$	VSWR-S	-	1.5:1	-

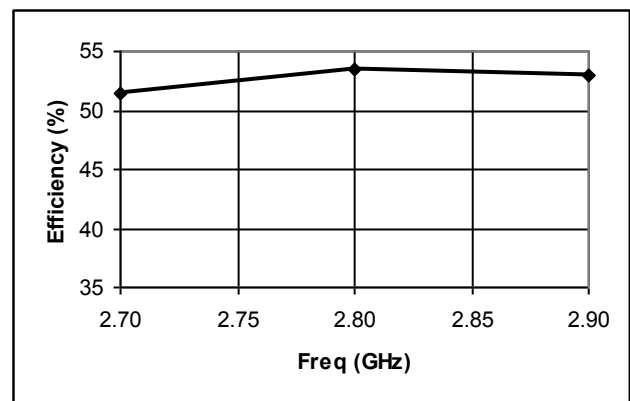
Typical RF Performance

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	Ic (A)	Eff (%)	RL (dB)	VSWR-S (1.5:1)	VSWR-T (2:1)
2.7	24	224	9.69	12.1	51.4	-15.6	S	P
2.8	24	217	9.56	11.3	53.4	-14.7	S	P
2.9	24	196	9.11	10.3	53.0	-10.6	S	P

Gain vs. Frequency

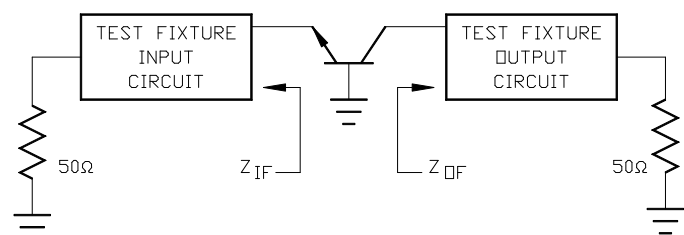


Collector Efficiency vs. Frequency



RF Test Fixture Impedance

F (GHz)	Z _{IF} (Ω)	Z _{OF} (Ω)
2.7	5.1 - j5.1	1.8 - j2.1
2.8	5.2 - j4.7	1.8 - j1.8
2.9	5.3 - j4.3	1.8 - j1.4



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